Amendments to the Claims:

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The following listing of claims will replace all prior versions, and listings, of claims in the application:

1. (Currently Amended) An electro-optical device, comprising, above a substrate:

scanning lines and data lines that intersect with each other to form a grid like pattern;

thin-film transistors, each of the thin film transistors being disposed in correspondence with intersections of one of the scanning lines and one of the data lines;

pixel electrodes respectively being disposed in correspondence with the thinfilm transistors;

a first light shielding film laminated between the data line and the pixel electrode; and

a storage capacitor including the first light shielding film and a capacitive electrode of pixel-electrode potential, laminated between the data line and the pixel electrode.

- 2. (Original) The electro-optical device according to claim 1, the thin-film transistor having a channel region which is formed in an intersection portion of the scanning line and the data line.
 - 3. (Canceled).
- 4. (Currently Amended) The electro-optical device according to elaim 3claim 1, the capacitive electrode being electrically connected to a semiconductor layer of the thin film transistor via a barrier layer forming a film of formed of the same film as the data line.
- 5. (Original) The electro-optical device according to claim 4, the barrier layer being formed along the data line and the scanning line.

	6.	(Currently Amended) The electro-optical device according to claim 1, the first
	light shielding	g film being formed along the data line and the scanning line. An electro-optical
	device, comp	rising, above a substrate:
		scanning lines and data lines that intersect with each other to form a grid-like
	pattern;	
		thin-film transistors, each of the thin-film transistors being disposed in
correspondence with intersections of one of the scanning lines and one of the data		ce with intersections of one of the scanning lines and one of the data lines;
_		pixel electrodes respectively being disposed in correspondence with the thin-
8	film transistors;	
		a first light shielding film laminated between the data line and the pixel
	electrode,	
		the first light shielding film being formed along the data line and the scanning
	line; and	
		a storage capacitor including the first light shielding film, laminated between
	the data line a	and the pixel electrode.
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- 7. (Original) The electro-optical device according to claim 6, the first light shielding film being formed in a grid configuration.
- 8. (Original) An electronic apparatus comprising an electro-optical device according to claim 1.